

DESCRIPTION

The MPM3805B is an automotive-grade, step-down module converter with a built-in inductor and power MOSFETs. It achieves 0.6A of peak output current from a 2.5V to 6V input voltage range, with excellent load and line regulation. The output voltage is fixed to 1.2V, so the device only requires input and output capacitors to complete the design.

The device's integrated inductor simplifies the power system design and provides easy, efficient use. Constant-on-time (COT) control provides fast transient response and eases loop stabilization. Fault protections include cycle-by-cycle current limiting and thermal shutdown (TSD).

The MPM3805B is ideal for a wide range of automotive applications, including small ECUs, camera modules, telematics, and infotainment systems. It is available in a small, surface-mounted QFN-12 (2.5mmx3.0mmx0.9mm) package.

FEATURES

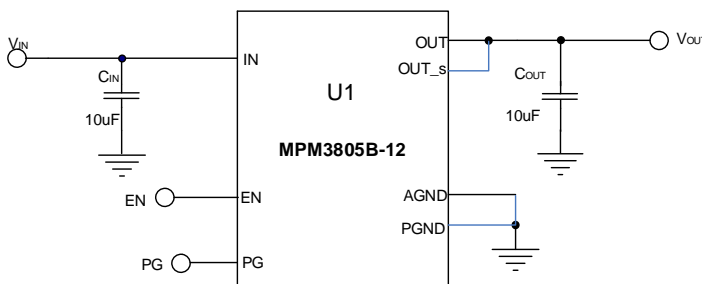
- Guaranteed Industrial/Automotive Temp
- Wide 2.5V to 6V Operating Input Range
- Fixed 1.2V Output
- Up to 0.6A Peak Output Current
- 100% Duty Cycle in Dropout Mode
- Forced Continuous Conduction Mode (CCM)
- EN and Power Good for Power Sequencing
- Cycle-by-Cycle Over-Current Protection
- Short-Circuit Protection with Hiccup Mode
- Only Requires Two External Ceramic Capacitors
- Total Solution Size of 6mmx3.8mm
- Available in a QFN-12 (2.5mmx3.0mmx0.9mm) Package
- Available in AEC-Q100 Grade 1

APPLICATIONS

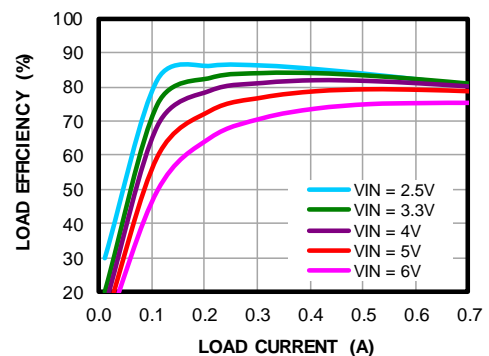
- Automotive ECUs
- Rear Cameras
- E-Calls
- Telematics
- Infotainment Systems

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TYPICAL APPLICATION



Efficiency vs. Load Current



ORDERING INFORMATION

Part Number*	Package	Top Marking	MSL Rating
MPM3805BGQB-12-AEC1	QFN-12 (2.5mmx3.0mmx0.9mm)	See Below	3

* For Tape & Reel, add suffix -Z (e.g. MPM3805BGQB-12-AEC1-Z).

TOP MARKING

BJB

YWW

LLL

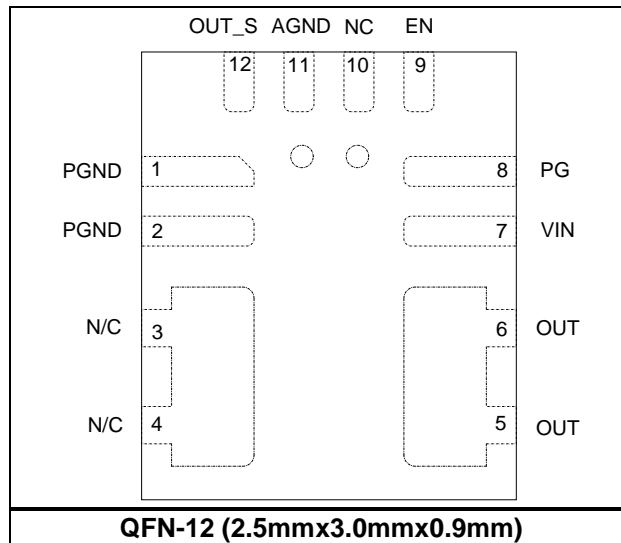
BJB: Product code of MPM3805BGQB-12-AEC1

Y: Year code

WW: Week code

LLL: Lot number

PACKAGE REFERENCE



PIN FUNCTIONS

Pin #	Name	Description
1, 2	PGND	Power ground.
3, 4	N/C	Internal SW pad.
5, 6	OUT	Output voltage power rail. Connect the load to OUT. An output capacitor is required.
7	VIN	Supply voltage. The MPM3805B operates from a 2.5V to 6V unregulated input voltage range. A decoupling capacitor is required to prevent large voltage spikes from appearing at the input. Place the decoupling capacitor as close to VIN as possible.
8	PG	Power good indicator. The output of PG is an open drain with an internal pull-up resistor to VIN. PG is pulled up to VIN when the feedback voltage (V_{FB}) is within 10% of the regulation level. If V_{FB} is out of the regulation range, PG is pulled low.
9	EN	On/off control.
10	NC	No internal connection.
11	AGND	Analog ground for internal control circuit.
12	OUT_S	Output voltage sense.

ABSOLUTE MAXIMUM RATINGS ⁽¹⁾

Supply voltage (V_{IN})	6.5V
All other pins.....	-0.3V to +6.5V
Junction temperature	150°C
Lead temperature	260°C
Continuous power dissipation ($T_A = 25^\circ\text{C}$) ⁽²⁾	1.9W
Storage temperature.....	-65°C to +150°C

ESD Rating

Human body model (HBM)	2kV
Charged device model (CDM).....	750V

Recommended Operating Conditions

Supply voltage (V_{IN})	2.5V to 6V
Output voltage (V_{OUT}).....	1.2V
Operating junction temp (T_J)	-40°C to +125°C

Thermal Resistance ⁽³⁾	θ_{JA}	θ_{JC}
QFN-12 (2.5mmx3.0mm).....	65.....	13...°C/W

Notes:

- 1) Exceeding these ratings may damage the device.
- 2) The maximum allowable power dissipation is a function of the maximum junction temperature T_J (MAX), the junction-to-ambient thermal resistance θ_{JA} , and the ambient temperature T_A . The maximum allowable continuous power dissipation at any ambient temperature is calculated by P_D (MAX) = $(T_J$ (MAX) - T_A) / θ_{JA} . Exceeding the maximum allowable power dissipation produces an excessive die temperature, causing the device to go into thermal shutdown. Internal thermal shutdown circuitry protects the device from permanent damage.
- 3) Measured on JESD51-7, 4-layer PCB.

ELECTRICAL CHARACTERISTICS

$V_{IN} = 5V$, $T_J = -40^{\circ}C$ to $+125^{\circ}C$, unless otherwise noted. Typical values are at $T_J = 25^{\circ}C$.

Parameter	Symbol	Condition	Min	Typ	Max	Units	
Input voltage	V_{IN}		2.5		6.0	V	
Output voltage accuracy	V_{OUT}	$I_{OUT} = 10mA$, $T_J = 25^{\circ}C$, $V_{IN} = 5V$	1.17	1.200	1.23	V	
		$I_{OUT} = 10mA$, $V_{IN} = 5V$, $T_J = -40^{\circ}C$ to $+125^{\circ}C$	1.164	1.2	1.236		
PFET switch on resistance	R_{DSON_P}			100	230	m Ω	
NFET switch on resistance	R_{DSON_N}			60	130	m Ω	
Inductor L value	L	Inductance value at 1MHz		0.47		μH	
Inductor DC resistance	R_{DCR}			120		m Ω	
Dropout resistance	R_{DR}	100% on duty		220		m Ω	
Switch leakage		$V_{EN} = 0V$, $V_{IN} = 6V$, $V_{SW} = 0V$ and $6V$, $T_J = 25^{\circ}C$		0	1	μA	
PFET current limit		$T_J = 25^{\circ}C$	1.6	2.1	2.6	A	
		$T_J = -40^{\circ}C$ to $+125^{\circ}C$	1.5		2.7		
On time	t_{ON}	$V_{IN} = 5V$	$T_J = 25^{\circ}C$	50	70	100	ns
			$T_J = -40^{\circ}C$ to $+125^{\circ}C$			110	
		$V_{IN} = 3.6V$	$T_J = 25^{\circ}C$	70	100	130	
			$T_J = -40^{\circ}C$ to $+125^{\circ}C$			140	
Switching frequency	f_{SW}	$V_{IN} = 3.6V$ to $5V$	$T_J = 25^{\circ}C$	2.7	3.5	4.2	MHz
			$T_J = -40^{\circ}C$ to $+125^{\circ}C$	2.4			
Minimum off time	$t_{MIN-OFF}$			60		ns	
Soft-start time	t_{SS-ON}			1.5		ms	
Power good upper trip threshold	PG_H	FB voltage in respect to the regulation		+10		%	
Power good lower trip threshold	PG_L			-10		%	
Power good delay	PG_D			50		μs	
Power good sink current capability	V_{PG-L}	Sink 1mA			0.4	V	
Power good logic high voltage	V_{PG-H}	$V_{IN} = 5V$, $V_{FB} = 0.6V$	4.9			V	
Power good internal pull-up resistor	R_{PG}			550		k Ω	

ELECTRICAL CHARACTERISTICS (continued)
 $V_{IN} = 5V$, $T_J = -40^{\circ}C$ to $+125^{\circ}C$, unless otherwise noted. Typical value are at $T_J = 25^{\circ}C$.

Parameter	Symbol	Condition	Min	Typ	Max	Units
Under-voltage lockout rising threshold			2.2	2.4	2.6	V
Under-voltage lockout hysteresis threshold				300		mV
EN input logic low voltage					0.4	V
EN input logic high voltage			1.2			V
EN input current		$V_{EN} = 2V$		1.5		μA
		$V_{EN} = 0V$		0.1	1	μA
Supply current (shutdown)		$V_{EN} = 0V$, $T_J = 25^{\circ}C$			1	μA
		$V_{EN} = 0V$, $T_J = -40^{\circ}C$ to $+125^{\circ}C$			10	
Supply current (quiescent)		$V_{EN} = 2V$, $V_{FB} = 0.63V$, $V_{IN} = 5V$, $T_J = 25^{\circ}C$		485	560	μA
		$V_{EN} = 2V$, $V_{FB} = 0.63V$, $V_{IN} = 5V$, $T_J = -40^{\circ}C$ to $+125^{\circ}C$			580	
Thermal shutdown ⁽⁴⁾				150		$^{\circ}C$
Thermal hysteresis ⁽⁴⁾				30		$^{\circ}C$

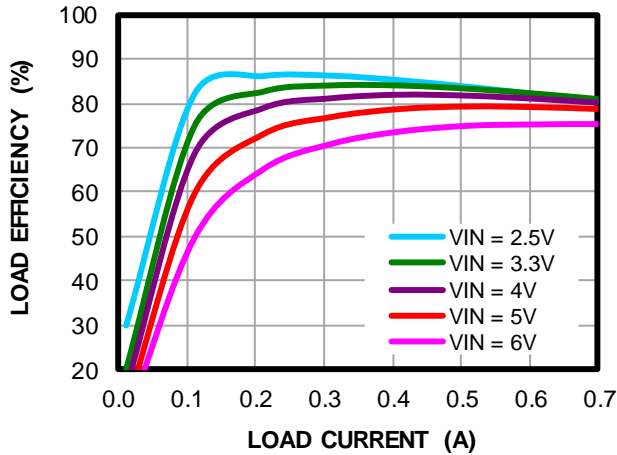
Note:

4) Not production tested, guaranteed by design.

TYPICAL PERFORMANCE CHARACTERISTICS

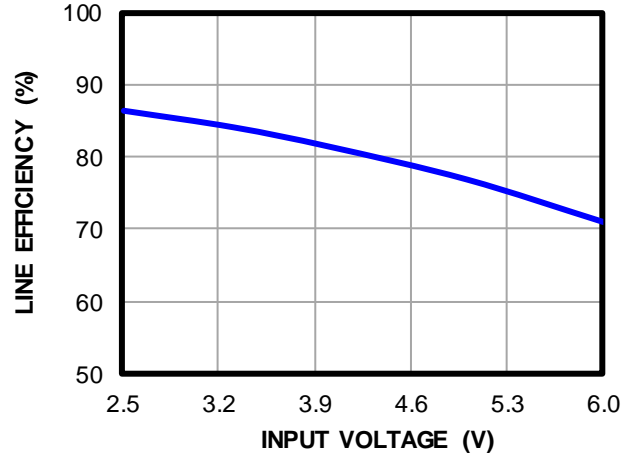
$V_{IN} = 5V$, $V_{OUT} = 1.2V$, $C_{IN} = 10\mu F$, $C_{OUT} = 20\mu F$, $T_A = 25^\circ C$, unless otherwise noted.

Efficiency vs. Load Current

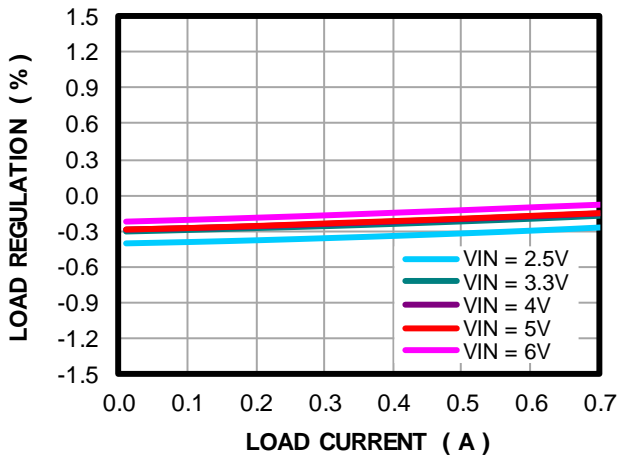


Line Efficiency

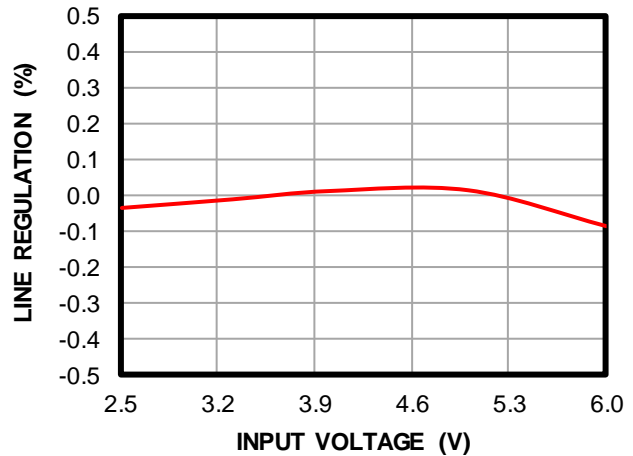
$I_{OUT} = 0.3A$



Load Regulation

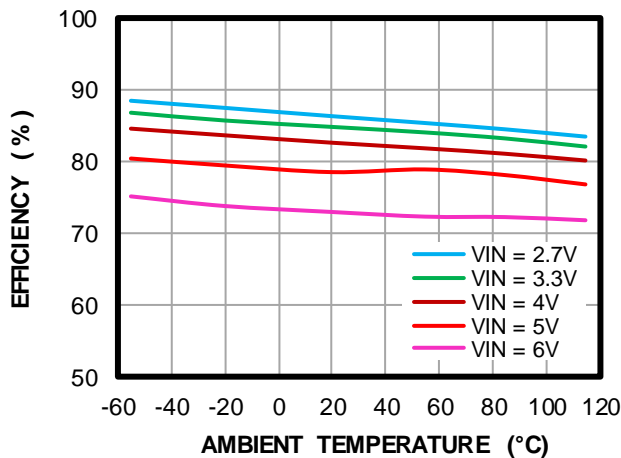


Line Regulation



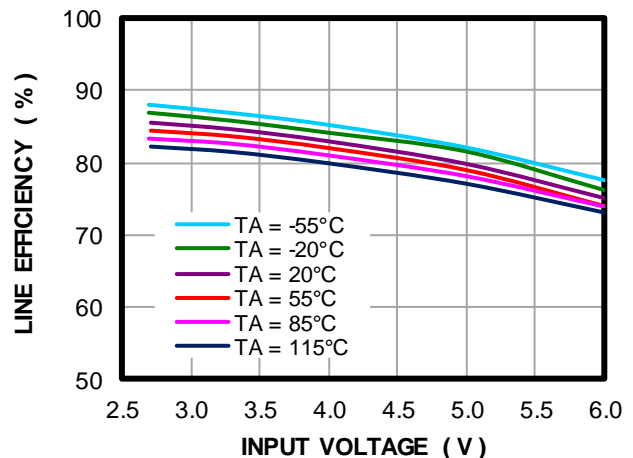
Load Efficiency vs. Temperature

$I_{OUT} = 0.35A$



Line Efficiency

$I_{OUT} = 0.45A$

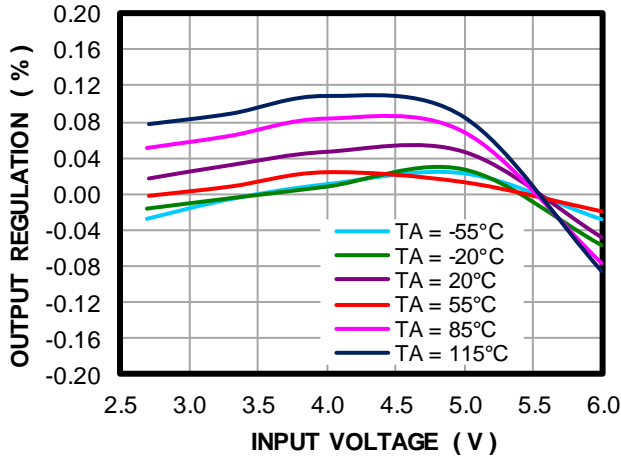


TYPICAL PERFORMANCE CHARACTERISTICS *(continued)*

$V_{IN} = 5V$, $V_{OUT} = 1.2V$, $C_{IN} = 10\mu F$, $C_{OUT} = 20\mu F$, $T_A = 25^\circ C$, unless otherwise noted.

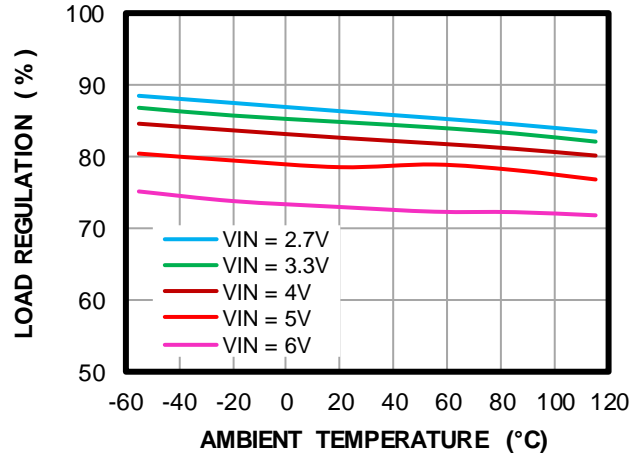
Line Regulation

$I_{OUT} = 0.45A$



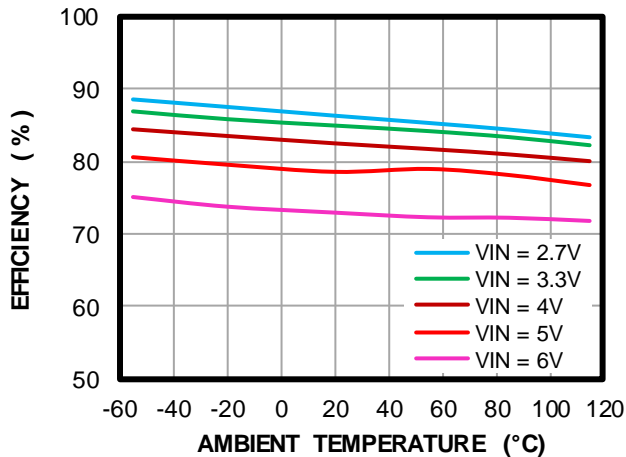
Load Regulation vs. Temperature

$I_{OUT} = 0.35A$



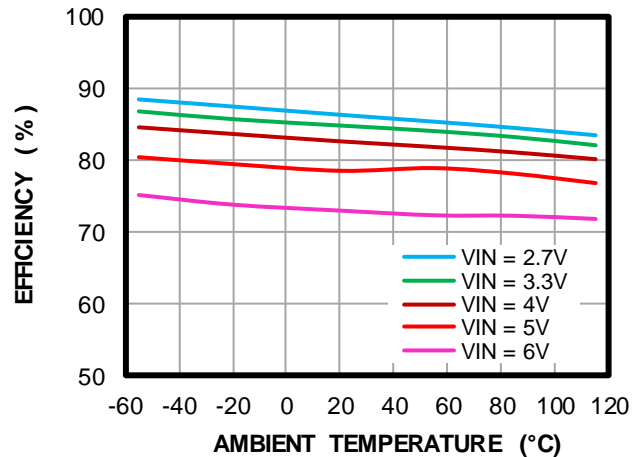
Efficiency vs. Temperature

$I_{OUT} = 0.35A$

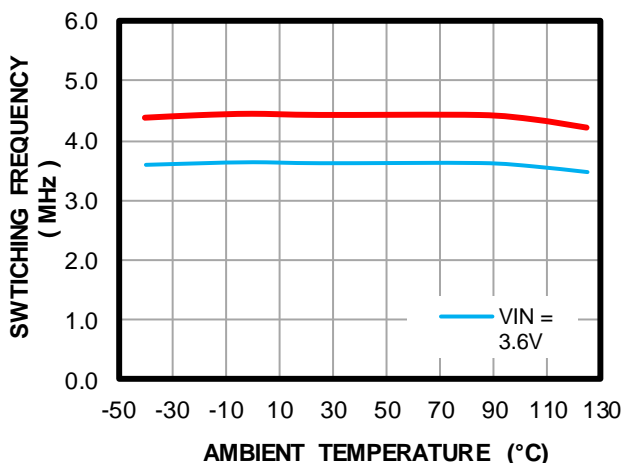


Line Efficiency vs. Temperature

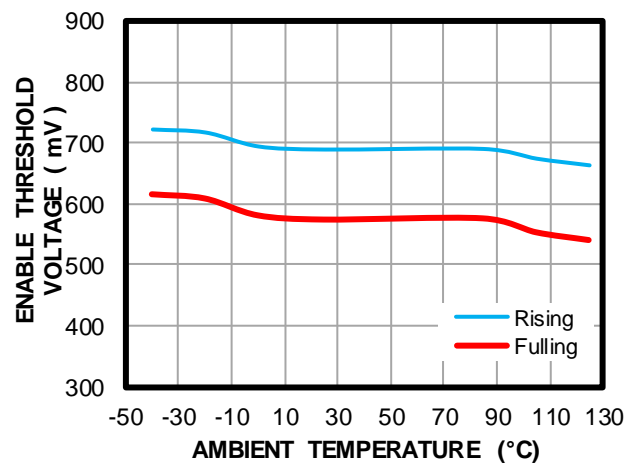
$I_{OUT} = 0.35A$



Switching Frequency vs. Temperature



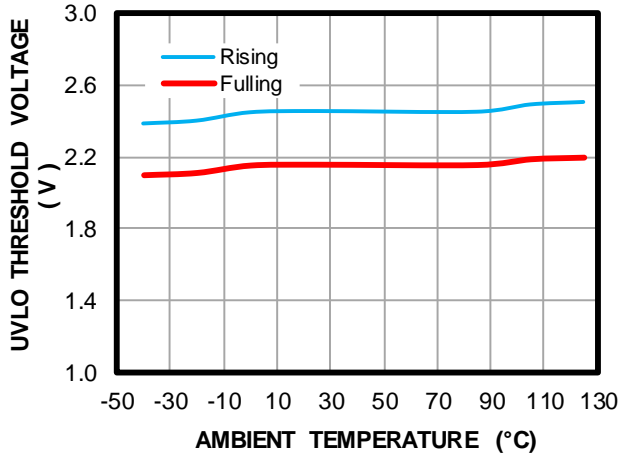
Enable Threshold Voltage vs. Temperature



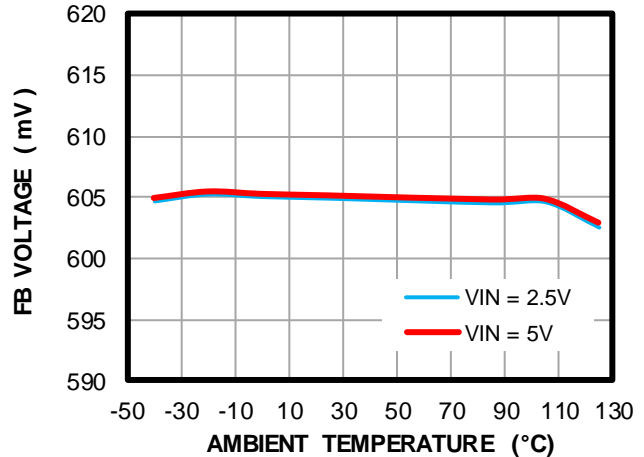
TYPICAL PERFORMANCE CHARACTERISTICS *(continued)*

$V_{IN} = 5V$, $V_{OUT} = 1.2V$, $C_{IN} = 10\mu F$, $C_{OUT} = 20\mu F$, $T_A = 25^\circ C$, unless otherwise noted.

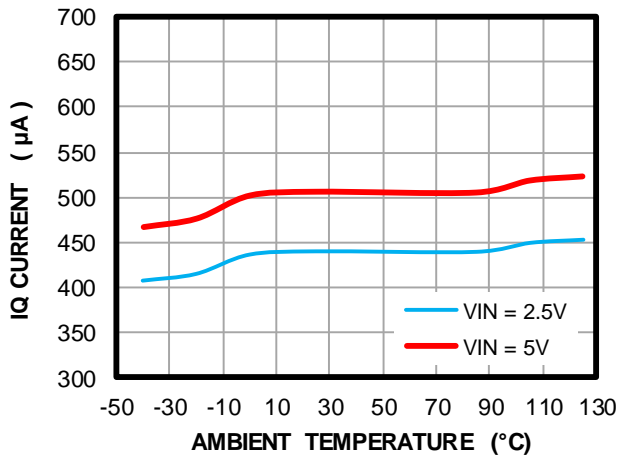
UVLO Threshold Voltage vs. Temperature



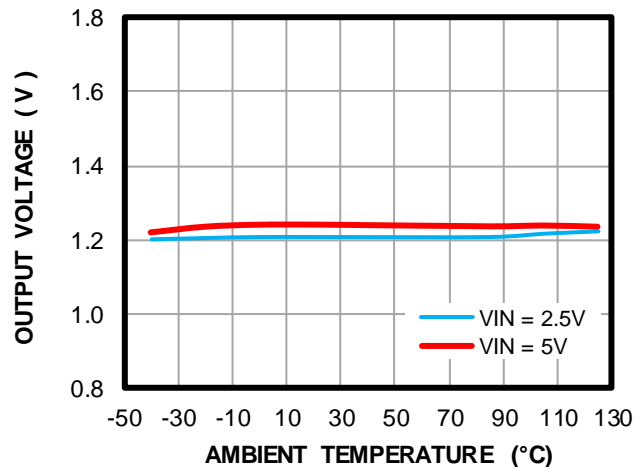
FB Voltage vs. Temperature



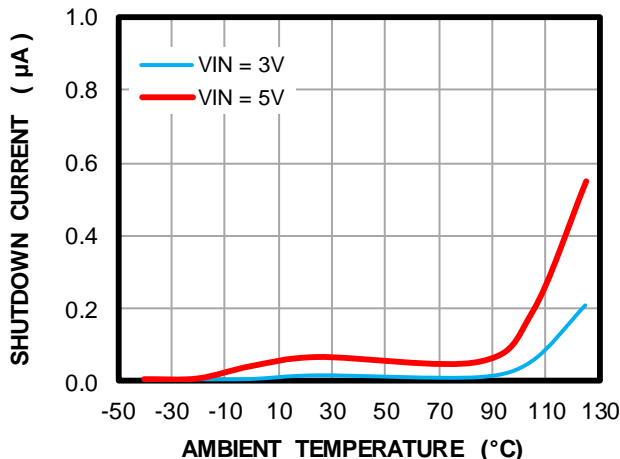
IQ Current vs. Temperature



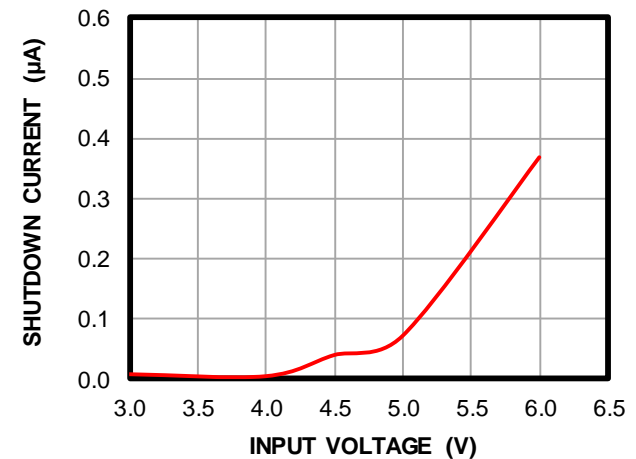
Output Voltage vs. Temperature



Shutdown Current vs. Temperature



Shutdown Current vs. VIN

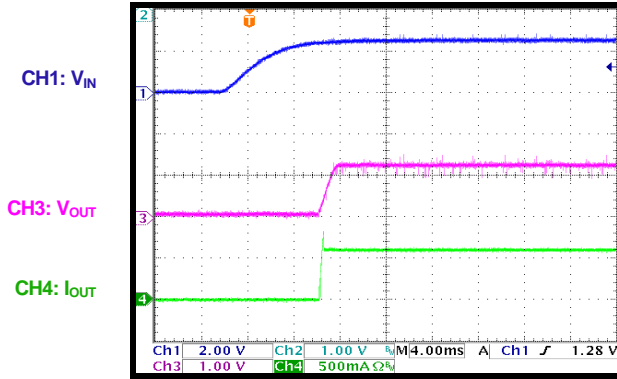


TYPICAL PERFORMANCE CHARACTERISTICS *(continued)*

$V_{IN} = 5V$, $V_{OUT} = 1.2V$, $C_{IN} = 10\mu F$, $C_{OUT} = 20\mu F$, $T_A = 25^\circ C$, unless otherwise noted.

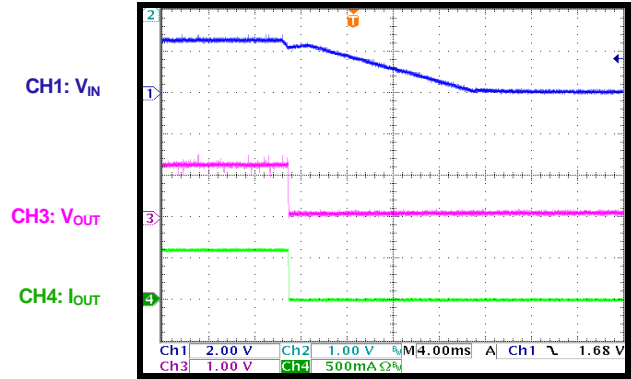
Start-Up

$V_{IN} = 2.5V$, $I_{OUT} = 0.6A$



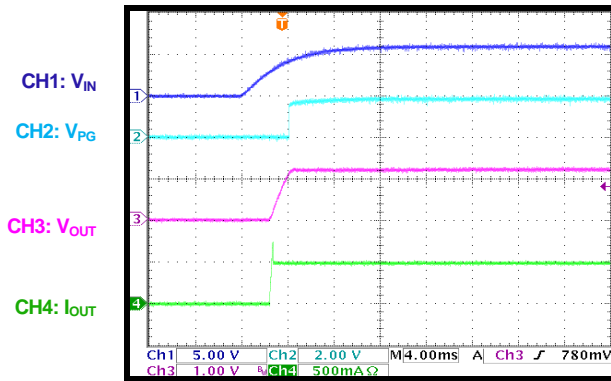
Shutdown

$V_{IN} = 2.5V$, $I_{OUT} = 0.6A$



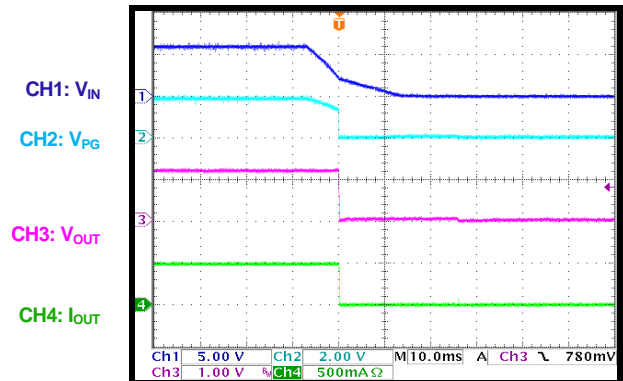
Start-Up

$V_{IN} = 6V$, $I_{OUT} = 0.5A$



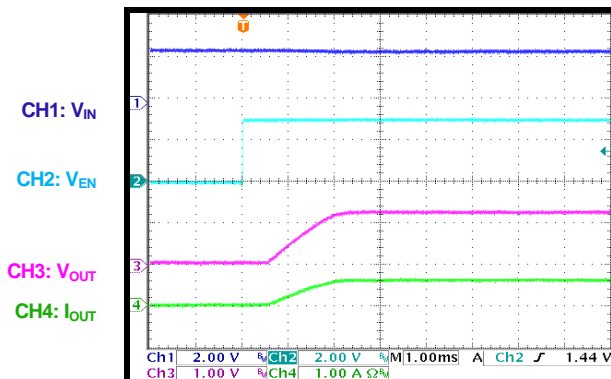
Shutdown

$V_{IN} = 6V$, $I_{OUT} = 0.5A$



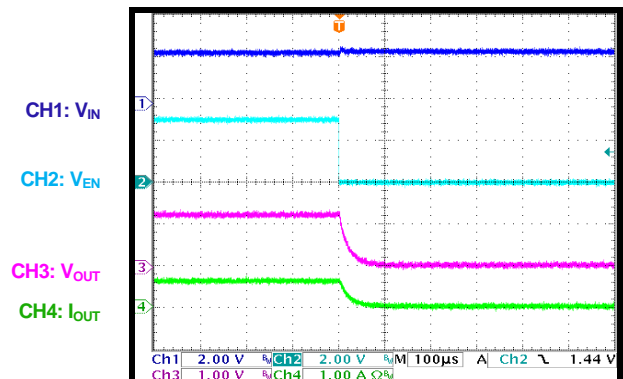
Enable On

$V_{IN} = 2.5V$, $I_{OUT} = 0.6A$



Enable Off

$V_{IN} = 2.5V$, $I_{OUT} = 0.6A$

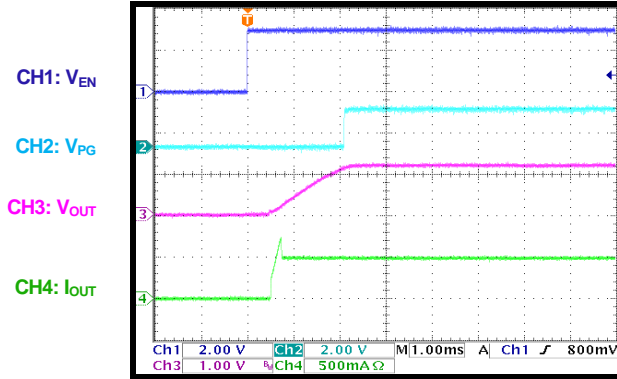


TYPICAL PERFORMANCE CHARACTERISTICS (continued)

$V_{IN} = 5V$, $V_{OUT} = 1.2V$, $C_{IN} = 10\mu F$, $C_{OUT} = 20\mu F$, $T_A = 25^\circ C$, unless otherwise noted.

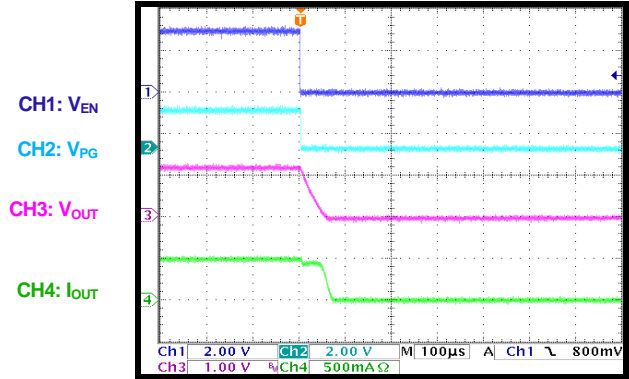
Enable On

$V_{IN} = 6V$, $I_{OUT} = 0.5A$



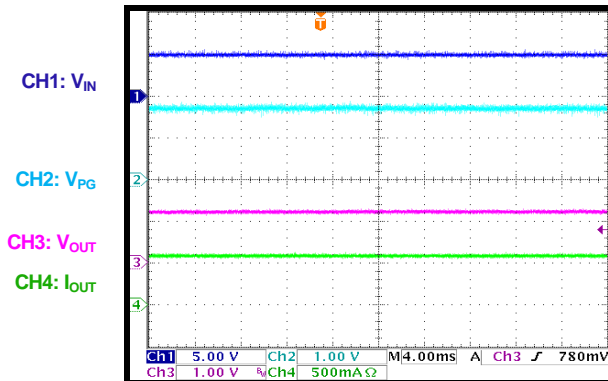
Enable Off

$V_{IN} = 6V$, $I_{OUT} = 0.5A$



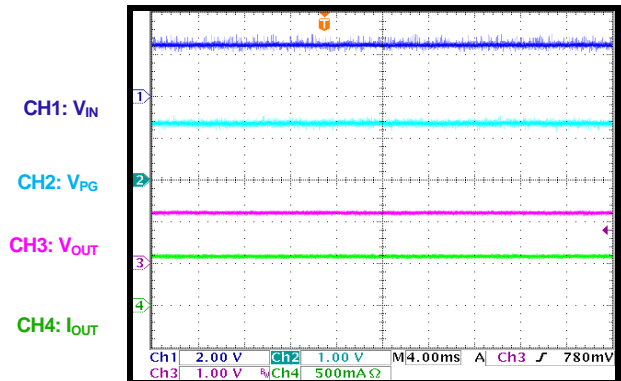
Steady State

$V_{IN} = 5V$, $I_{OUT} = 0.6A$



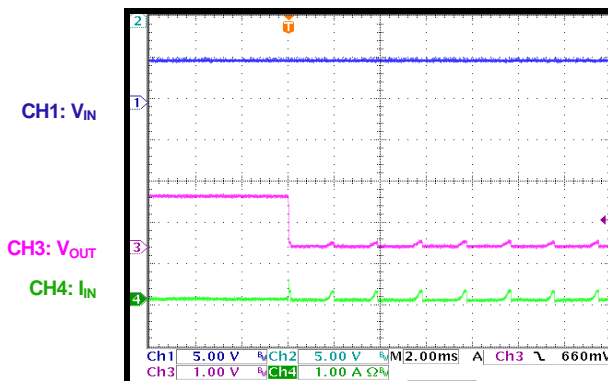
Steady State

$V_{IN} = 2.5V$, $I_{OUT} = 0.6A$



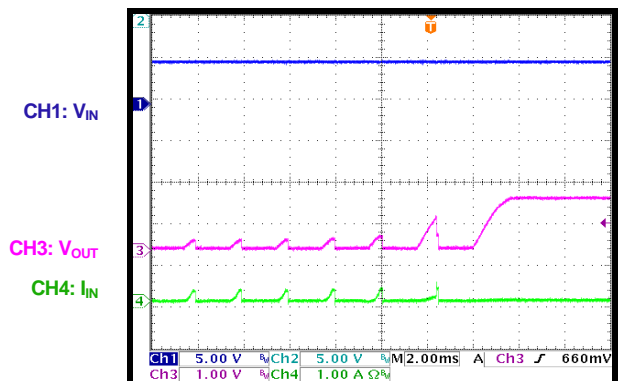
Short Circuit

$V_{IN} = 5V$



Short-Circuit Recovery

$V_{IN} = 5V$

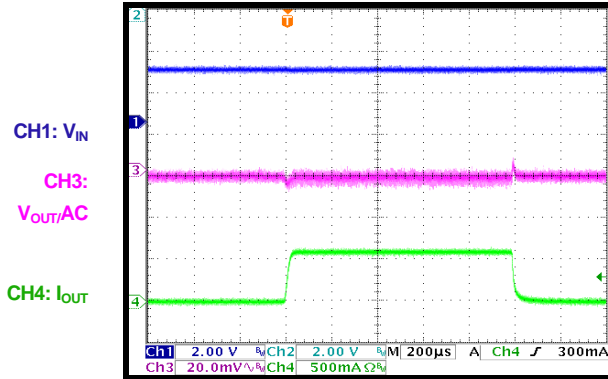


TYPICAL PERFORMANCE CHARACTERISTICS *(continued)*

$V_{IN} = 5V$, $V_{OUT} = 1.2V$, $C_{IN} = 10\mu F$, $C_{OUT} = 20\mu F$, $T_A = 25^\circ C$, unless otherwise noted.

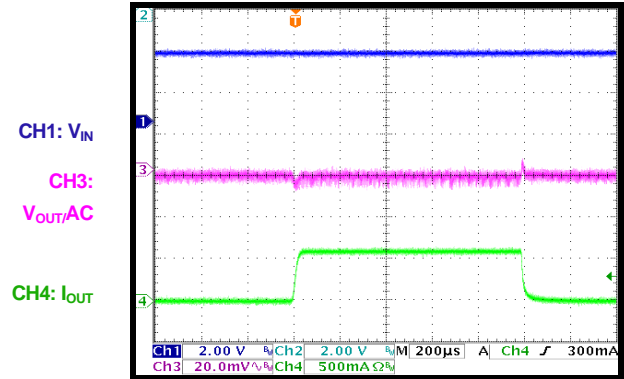
Transient Response

$V_{IN} = 2.5V$, $I_{OUT} = 0A$ to $0.6A$, $0.25A/\mu s$



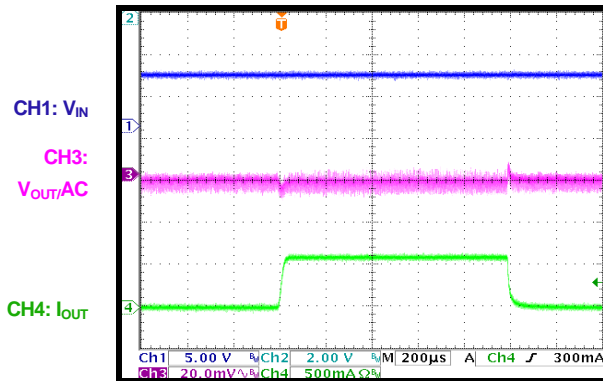
Transient Response

$V_{IN} = 3.3V$, $I_{OUT} = 0A$ to $0.6A$, $0.25A/\mu s$



Transient Response

$V_{IN} = 6V$, $I_{OUT} = 0A$ to $0.6A$, $0.25A/\mu s$



FUNCTIONAL BLOCK DIAGRAM

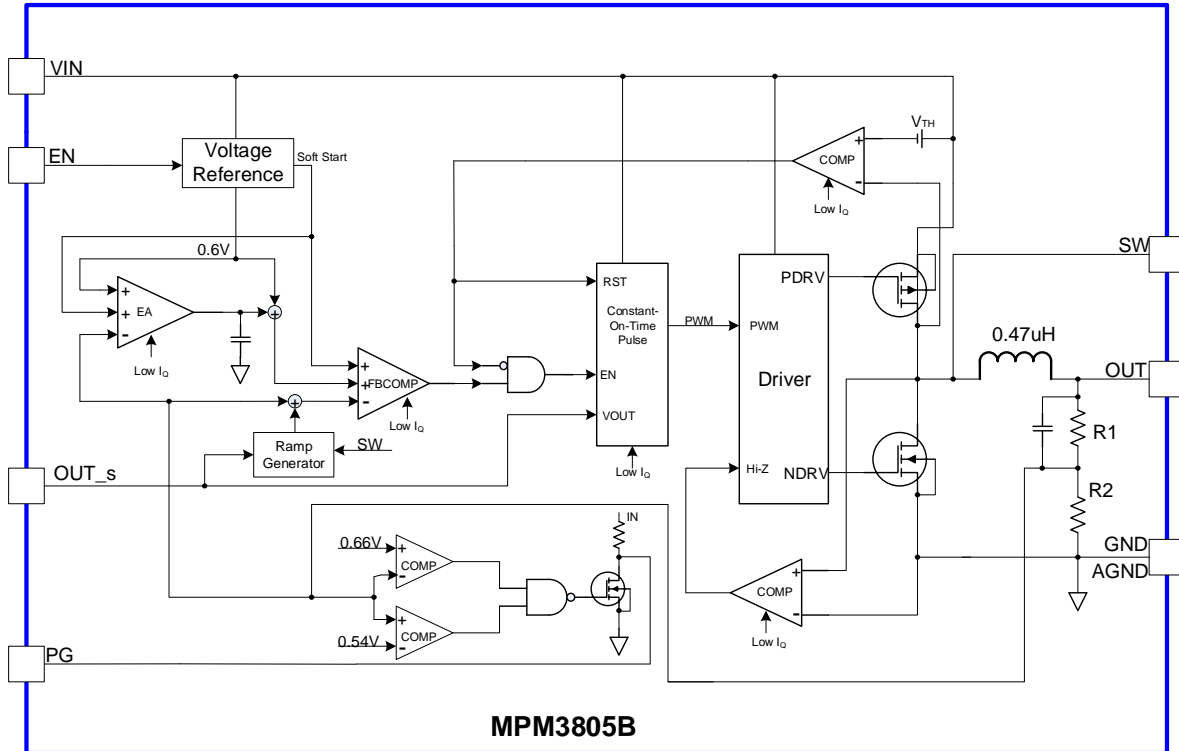


Figure 1: Functional Block Diagram

OPERATION

The MPM3805B's integrated inductor simplifies the schematic and layout design. Only input and output capacitors are required to complete the design. The MPM3805B uses constant-on-time (COT) control with input voltage feed forward to stabilize the switching frequency over the full input range. At light-load, the device employs proprietary control of the low-side switch and inductor current to improve efficiency. It is available in a small, surface-mounted QFN-12 (2.5mmx3.0mmx0.9mm) package.

Constant-On-Time Control (COT)

Compared to fixed-frequency pulse-width modulation (PWM) control, constant-on-time control (COT) offers a simpler control loop and faster transient response. Using input voltage feed forward, the MPM3805B maintains a nearly constant switching frequency across the input and output voltage range.

The on time of the switching pulse can be estimated with Equation (1):

$$t_{ON} = \frac{V_{OUT}}{V_{IN}} \times 0.28\mu s \quad (1)$$

To prevent inductor current runaway during the load transition, the MPM3805B fixes the minimum off time to 60ns. However, this time limit does not affect operation in a steady state.

The MPM3805B works in forced continuous conduction mode (CCM).

Enable (EN)

If the input voltage exceeds the under-voltage lockout (UVLO) threshold (typically 2.3V), the MPM3805B is enabled by pulling EN above 1.2V. Float EN floating or pull it to ground to disable the MPM3805B. There is an internal 1M Ω resistor from EN to ground.

Soft Start (SS)

The MPM3805B has a built-in soft start that ramps up the output voltage in a controlled slew rate. This avoids overshoot at start-up. The soft-start time is about 1.5ms.

Power Good Indicator (PGOOD)

The MPM3805B has an open drain with a 550k Ω pull-up resistor pin for the power good indicator

(PGOOD). When the feedback voltage (V_{FB}) is within $\pm 10\%$ of the regulation voltage (e.g. 0.6V), PGOOD is pulled up to IN by the internal resistor. If V_{FB} is out of the $\pm 10\%$ window, PGOOD is pulled down to ground by an internal MOSFET. The MOSFET has a maximum $R_{DS(ON)}$ below 400 Ω .

Current Limit

The MPM3805B has a typical 2.1A current limit for the high-side switch. When the high-side switch reaches the current limit, the MPM3805B reaches the hiccup threshold until the current decreases. This prevents the inductor current from continuing to build, which could damage to the components.

Short Circuit and Recovery

The MPM3805B enters short-circuit protection (SCP) mode when the current limit is reached. It tries to recover from the short circuit with hiccup mode. When an SCP condition occurs, the MPM3805B disables the output power stage, discharges the soft-start capacitor, then automatically tries to soft start again. If the short-circuit condition remains after the soft start ends, The MPM3805B repeats the cycle until the short circuit disappears, and the output rises back to the regulation level.

APPLICATION INFORMATION

COMPONENT SELECTION

Selecting the Input Capacitor

The step-down converter has a discontinuous input current, and requires a capacitor to supply the AC current while maintaining the DC input voltage. For optimal performance, use low-ESR capacitors. Ceramic capacitors with X5R or X7R dielectrics are highly recommended due to their low ESR and small temperature coefficients. For most applications, a 10 μ F capacitor is sufficient.

For an output capacitor, a 22 μ F capacitor may be needed to enhance system stability.

Since the input capacitor absorbs the input switching current, it requires an adequate ripple current rating. The RMS current in the input capacitor can be estimated with Equation (2):

$$I_{C1} = I_{LOAD} \times \sqrt{\frac{V_{OUT}}{V_{IN}} \times \left(1 - \frac{V_{OUT}}{V_{IN}}\right)} \quad (2)$$

The worst-case condition occurs at $V_{IN} = 2V_{OUT}$, calculated with Equation (3):

$$I_{C1} = \frac{I_{LOAD}}{2} \quad (3)$$

For simplification, choose an input capacitor that has an RMS current rating greater than half of the maximum load current.

The input capacitor can be electrolytic, tantalum or ceramic. When using electrolytic or tantalum capacitors, add a small, high-quality ceramic capacitor (e.g. 0.1 μ F) as close to the IC as possible. When using ceramic capacitors, ensure that they have enough capacitance to provide sufficient charge to prevent an excessive voltage ripple at the input. The input voltage ripple caused by capacitance can be estimated with Equation (4):

$$\Delta V_{IN} = \frac{I_{LOAD}}{f_{SW} \times C1} \times \frac{V_{OUT}}{V_{IN}} \times \left(1 - \frac{V_{OUT}}{V_{IN}}\right) \quad (4)$$

Selecting the Output Capacitor

The output capacitor (C_{OUT}) is required to maintain the DC output voltage. Ceramic capacitors are recommended. Low-ESR

capacitors are recommended to maintain a low output voltage ripple. The output voltage ripple can be calculated with Equation (5):

$$\Delta V_{OUT} = \frac{V_{OUT}}{f_{SW} \times L_1} \times \left(1 - \frac{V_{OUT}}{V_{IN}}\right) \times \left(R_{ESR} + \frac{1}{8 \times f_s \times C2}\right) \quad (5)$$

Where L_1 is the inductor value, and R_{ESR} is the equivalent series resistance (ESR) value of the output capacitor (L_1 is 0.47 μ H).

When using ceramic capacitors, the capacitance dominates impedance at the switching frequency, and causes most of the output voltage ripple. For simplification, the output voltage ripple can be estimated with Equation (6):

$$\Delta V_{OUT} = \frac{V_{OUT}}{8 \times f_{SW}^2 \times L_1 \times C2} \times \left(1 - \frac{V_{OUT}}{V_{IN}}\right) \quad (6)$$

When using tantalum or electrolytic capacitors, the ESR dominates the impedance at the switching frequency. For simplification, the output ripple can be calculated with Equation (7):

$$\Delta V_{OUT} = \frac{V_{OUT}}{f_{SW} \times L_1} \times \left(1 - \frac{V_{OUT}}{V_{IN}}\right) \times R_{ESR} \quad (7)$$

The characteristics of the output capacitor affect the stability of the regulation system.

PCB Layout Guidelines

Efficient PCB layout is critical for stable operation. The device's integrated inductor simplifies the schematic and layout design. Input and output capacitors are required to complete the design. For the best results, refer to Figure 3 and Figure 4 and follow the guidelines below:

1. Place the high-current paths (PGND, IN and OUT) close to the device with short, direct, and wide traces.
2. Place the input capacitor as close to IN and PGND as possible.
3. Keep the switching node away from the feedback network.

For additional device applications, refer to the related evaluation board datasheets.

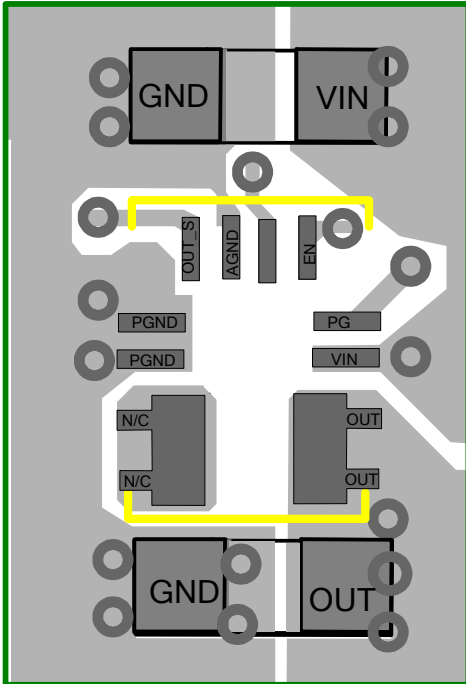


Figure 2: Top View of PCB Layout

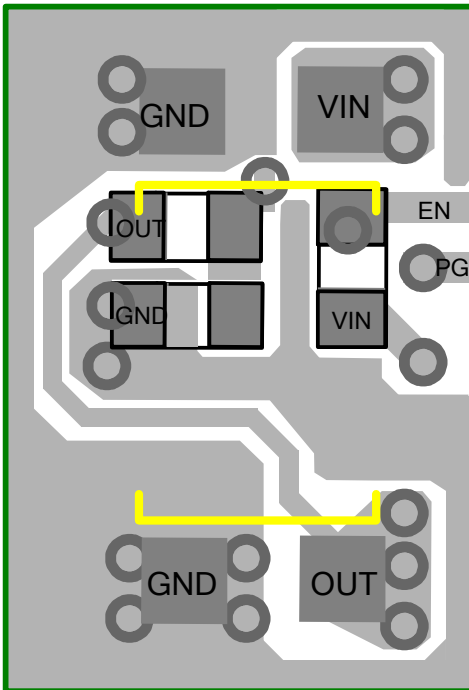


Figure 3: Bottom View of PCB Layout

TYPICAL APPLICATION CIRCUIT

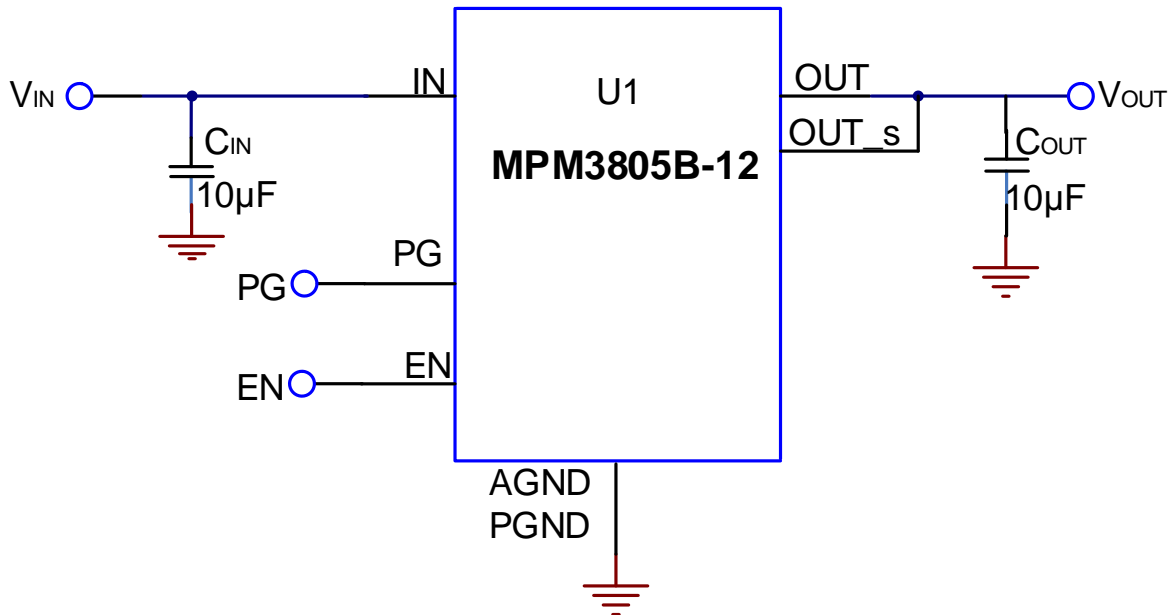
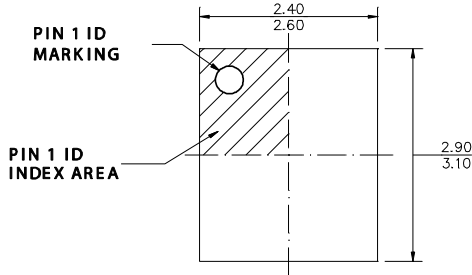


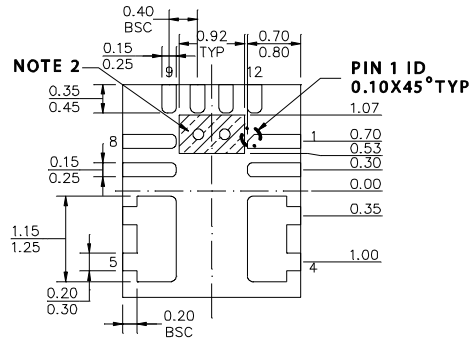
Figure 4: Typical Application Circuit

PACKAGE INFORMATION

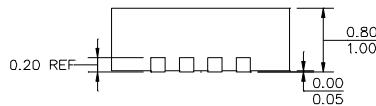
QFN-12 (2.5mmx3.0mmx0.9mm)



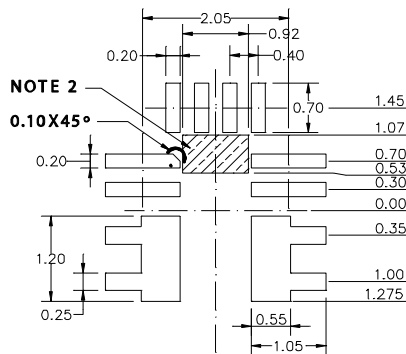
TOP VIEW



BOTTOM VIEW



SIDE VIEW



RECOMMENDED LAND PATTERN

NOTE:

- 1) ALL DIMENSIONS ARE IN MILLIMETERS
- 2) SHADED AREA IS THE KEEPOUT ZONE. THE EXPOSED BOTTOM METAL PADS ENCLOSED BY THIS ZONE IS NOT TO BE CONNECTED TO ANY PCB METAL TRACE & VIA ELECTRICALLY OR MECHANICALLY.
- 3) EXPOSED PADDLE SIZE DOES NOT INCLUDE MOLD FLASH.
- 4) LEAD COPLANARITY SHALL BE 0.10 MILLIMETERS MAX
- 5) JEDEC REFERENCE IS MQ220.
- 6) DRAWING IS NOT TO SCALE